



PJD25N04-AU

40V N-Channel Enhancement Mode MOSFET

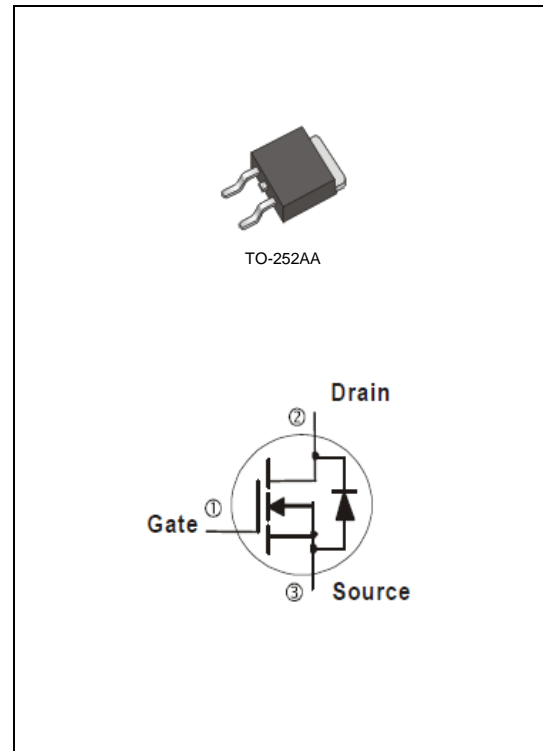
Voltage	40 V	Current	21 A
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Features

- $R_{DS(ON)}$, $V_{GS}@10V$, $I_D@12A < 32m\Omega$
- $R_{DS(ON)}$, $V_{GS}@4.5V$, $I_D@10A < 40m\Omega$
- High switching speed
- Improved dv/dt capability
- Low Gate Charge
- Low reverse transfer capacitance
- AEC-Q101 qualified
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

Mechanical Data

- Case : TO-252AA Package
- Terminals : Solderable per MIL-STD-750, Method 2026
- Weight : 0.0104 ounces, 0.297grams



Maximum Ratings and Thermal Characteristics ($T_A=25^\circ C$ unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS
Drain-Source Voltage		V_{DS}	40	V
Gate-Source Voltage		V_{GS}	± 20	
Continuous Drain Current	$T_C=25^\circ C$	I_D	21	A
	$T_C=100^\circ C$		13.2	
Pulsed Drain Current ^(Note 1)	$T_C=25^\circ C$	I_{DM}	80	
Power Dissipation	$T_C=25^\circ C$	P_D	30	W
	$T_C=100^\circ C$		15	
Continuous Drain Current	$T_A=25^\circ C$	I_D	5.9	A
	$T_A=70^\circ C$		4.7	
Power Dissipation	$T_A=25^\circ C$	P_D	2.4	W
Power Dissipation	$T_A=70^\circ C$		1.6	
Operating Junction and Storage Temperature Range		T_J, T_{STG}	-55~175	$^\circ C$
Typical Thermal Resistance ^(Note 4,5)	Junction to Case	$R_{\theta JC}$	5.0	$^\circ C/W$
	Junction to Ambient	$R_{\theta JA}$	62.5	

- Limited only By Maximum Junction Temperature



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Electrical Characteristics ($T_A=25^\circ\text{C}$ unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV_{DSS}	$V_{GS}=0V, I_D=250\mu A$	40	-	-	V
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}, I_D=250\mu A$	1.2	1.8	2.5	
Drain-Source On-State Resistance	$R_{DS(on)}$	$V_{GS}=10V, I_D=12A$	-	26	32	m Ω
		$V_{GS}=4.5V, I_D=10A$	-	32	40	
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS}=40V, V_{GS}=0V$	-	-	1.0	μA
Gate-Source Leakage Current	I_{GSS}	$V_{GS}=\pm 20V, V_{DS}=0V$	-	-	± 100	nA
Dynamic (Note 6)						
Total Gate Charge	Q_g	$V_{DS}=20V, I_D=5A,$ $V_{GS}=4.5V$ (Note 3)	-	4.4	-	nC
Gate-Source Charge	Q_{gs}		-	1.3	-	
Gate-Drain Charge	Q_{gd}		-	1.7	-	
Input Capacitance	C_{iss}	$V_{DS}=25V, V_{GS}=0V,$ $f=1.0\text{MHZ}$	-	425	-	pF
Output Capacitance	C_{oss}		-	48	-	
Reverse Transfer Capacitance	C_{rss}		-	36	-	
Turn-On Delay Time	$t_{d(on)}$	$V_{DD}=20V, I_D=1A,$ $V_{GS}=4.5V, R_G=25\Omega$ (Note 3)	-	9.4	-	ns
Turn-On Rise Time	t_r		-	29	-	
Turn-Off Delay Time	$t_{d(off)}$		-	21	-	
Turn-Off Fall Time	t_f		-	29	-	
Drain-Source Diode						
Maximum Continuous Drain-Source Diode Forward Current	I_S	---	-	-	21	A
Diode Forward Voltage	V_{SD}	$I_S=1A, V_{GS}=0V$	-	0.75	1	V

NOTES :

1. Pulse width $\leq 300\mu s$, Duty cycle $\leq 2\%$.
2. Essentially independent of operating temperature typical characteristics.
3. Repetitive rating, pulse width limited by junction temperature $T_{J(MAX)}=150^\circ\text{C}$. Ratings are based on low frequency and duty cycles to keep initial $T_J=25^\circ\text{C}$.
4. The maximum current rating is package limited.
5. $R_{\theta JA}$ is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch² with 2oz.square pad of copper.
6. Guaranteed by design, not subject to production testing.



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TYPICAL CHARACTERISTIC CURVES

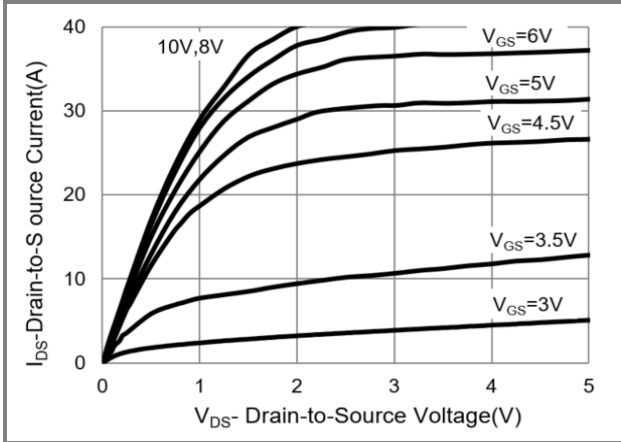


Fig.1 Output Characteristics

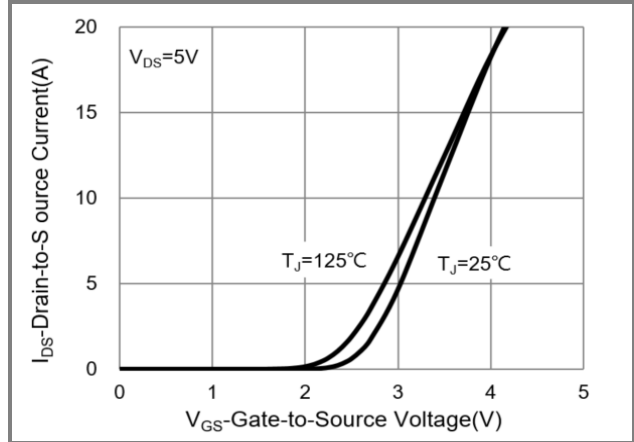


Fig.2 Transfer Characteristics

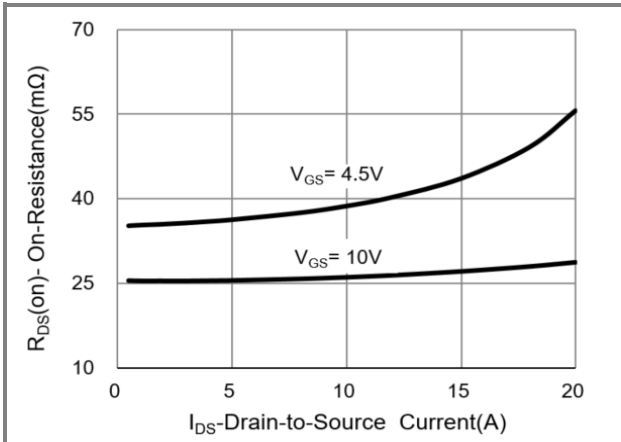


Fig.3 On-Resistance vs. Drain Current

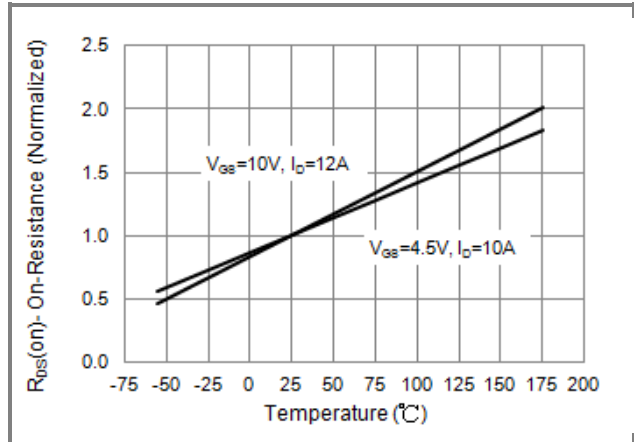


Fig.4 On-Resistance vs. Junction temperature

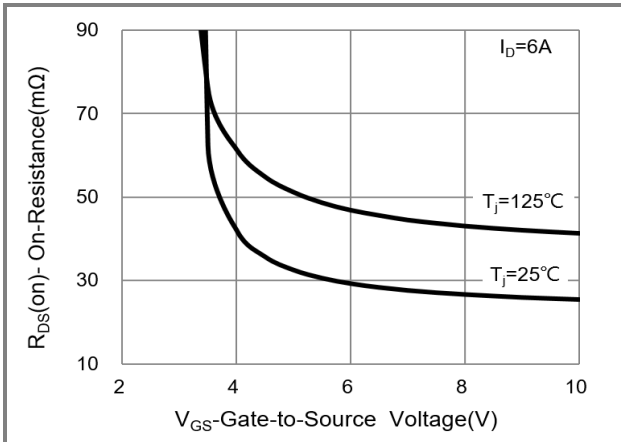


Fig.5 On-Resistance Variation with V_{GS}

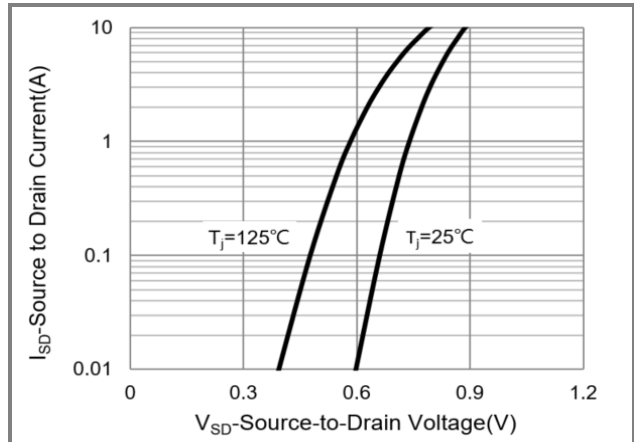


Fig.6 Source-Drain Diode Forward Voltage



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TYPICAL CHARACTERISTIC CURVES

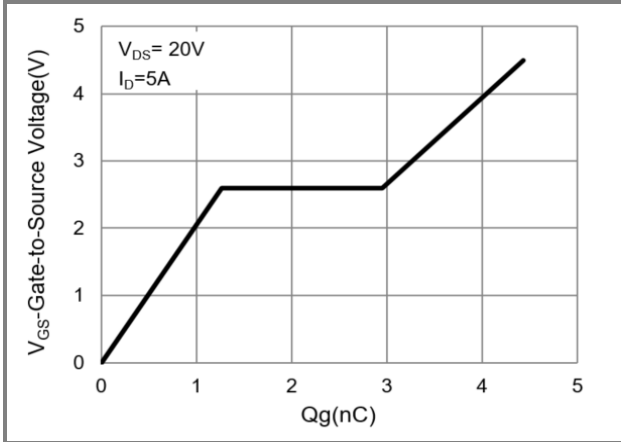


Fig.7 Gate-Charge Characteristics

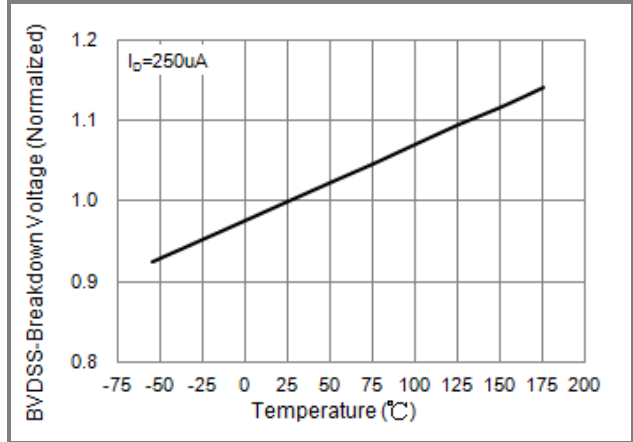


Fig.8 Breakdown Voltage Variation vs. Temperature

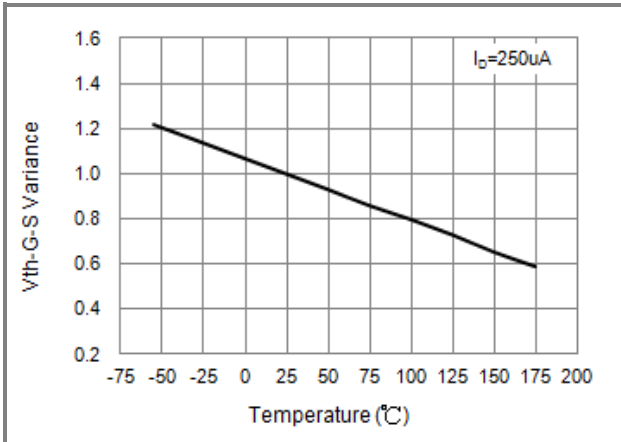


Fig.9 Threshold Voltage Variation with Temperature

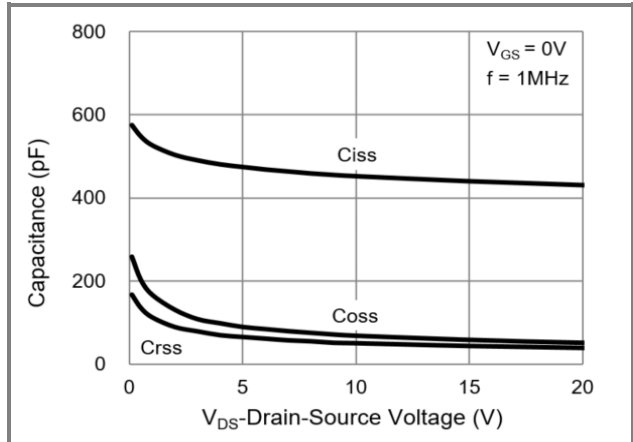


Fig.10 Capacitance vs. Drain-Source Voltage

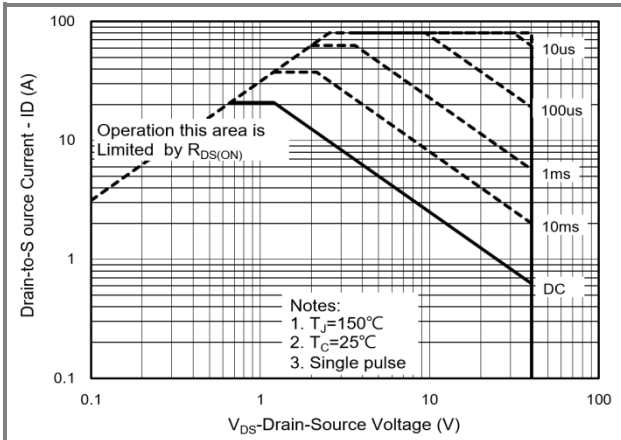


Fig.11 Maximum Safe Operating Area

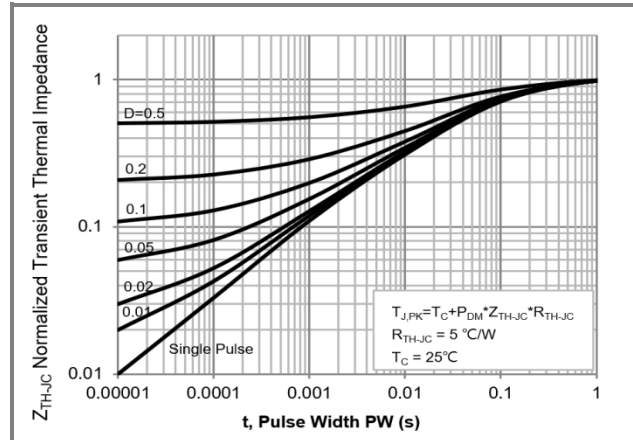


Fig.12 Normalized Transient Thermal Impedance

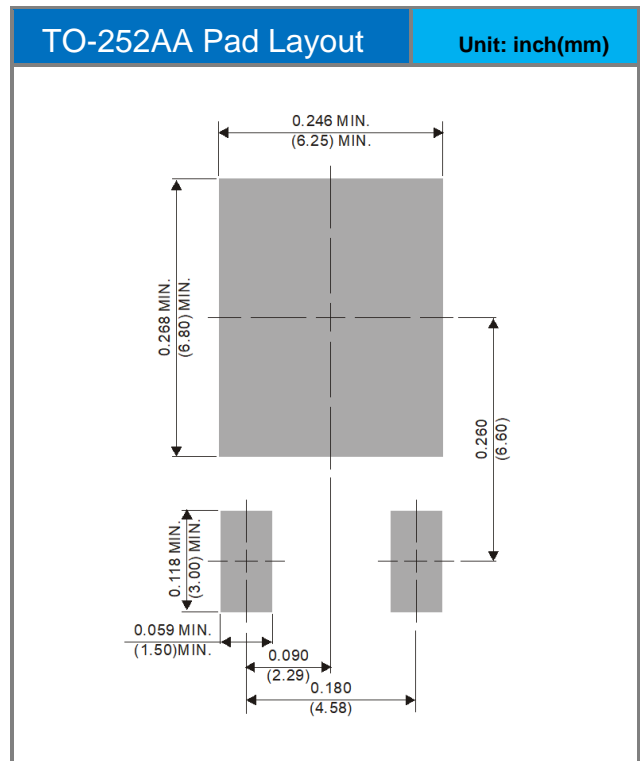
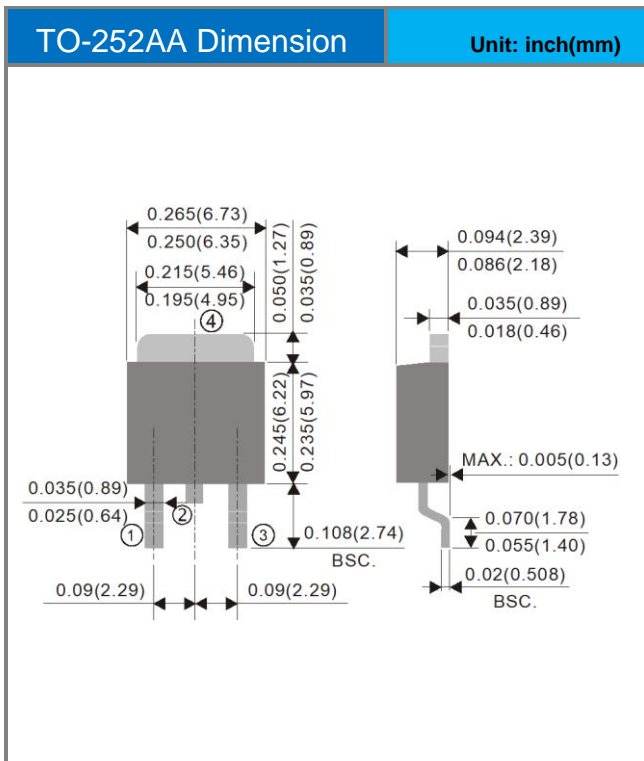


PJD25N04-AU

Part No Packing Code Version

Part No Packing Code	Package Type	Packing Type	Marking	Version
PJD25N04-AU_L2_000A1	TO-252AA	3,000pcs / 13" reel	D25N04	Halogen free

Packaging Information & Mounting Pad Layout





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